



-JPW

Docket No.: 050432-0395

PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of	:	Customer Number: 20277
Akif SULTAN, et al.	:	Confirmation Number: 6644
Application No.: 10/759,171	:	Group Art Unit: 2812
Filed: January 20, 2004	:	Examiner: S. Isaac

For: METHOD OF FORMING MINIATURIZED POLYCRYSTALLINE SILICON GATE
ELECTRODES USING SELECTIVE OXIDATION

AMENDMENT

Mail Stop Amendment
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Sir:

The following Amendment and Remarks are submitted in response to the Office Action
dated February 25, 2005.